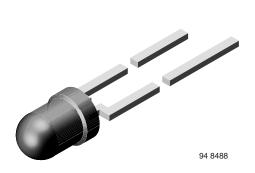
VSLB3948



Vishay Semiconductors

High Speed Infrared Emitting Diode, 940 nm, GaAIAs, MQW



DESCRIPTION

VSLB3948 is a high speed infrared emitting diode in GaAlAs, MQW technology, molded in a clear plastic package.

FEATURES

- Package type: leaded
- Package form: T-1, clear epoxy
- Dimensions: Ø 3 mm
- High speed
- High radiant power
- · Low forward voltage
- · Suitable for high pulse current operation
- Angle of half intensity: $\varphi = \pm 22^{\circ}$
- Peak wavelength: $\lambda_p = 940 \text{ nm}$
- · Good spectral matching to Si photodetectors
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

Infrared remote control units

PRODUCT SUMMARY COMPONENT I_e (mW/sr) φ (deg) λ_p (nm) t_r (ns) VSLB3948 ± 22 940 15 65

Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION							
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM				
VSLB3948	Bulk	MOQ: 5000 pcs, 5000 pcs/bulk	T-1				

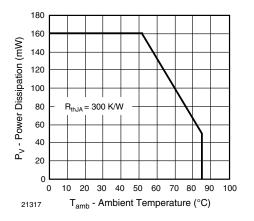
Note

MOQ: minimum order guantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
Reverse voltage		V _R	5	V			
Forward current		١ _F	100	mA			
Peak forward current	$t_p/T = 0.1, t_p = 100 \ \mu s$	I _{FM}	500	mA			
Surge forward current	t _p = 100 μs	I _{FSM}	1	А			
Power dissipation		Pv	160	mW			
Junction temperature		Тj	100	°C			
Operating temperature range		T _{amb}	-25 to +85	°C			
Storage temperature range		T _{stg}	-40 to +100	°C			
Soldering temperature	$t \leq 5$ s, 2 mm from case	T _{sd}	260	°C			
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R _{thJA}	300	K/W			



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Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

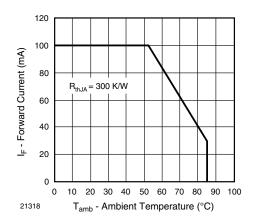


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Forward voltage	I _F = 100 mA, t _p = 20 ms	V _F	1.22	1.42	1.62	V	
Temperature coefficient of V _F	I _F = 1 mA	TK _{VF}		-1.5		mV/K	
Reverse current	V _R = 5 V	I _R			10	μA	
Junction capacitance	$V_R = 0 V$, f = 1 MHz, E = 0 mW/cm ²	CJ		21		pF	
Radiant intensity	I _F = 100 mA, t _p = 20 ms	l _e	32	65	110	mW/sr	
Radiant power	I _F = 100 mA, t _p = 20 ms	φe		40		mW	
Temperature coefficient of radiant	I _F = 1 mA	TKφe		-1.1		%/K	
power	I _F = 100 mA	TKφe		-0.51		%/K	
Angle of half intensity		φ		± 22		deg	
Peak wavelength	I _F = 30 mA	λρ		940		nm	
Spectral bandwidth	I _F = 30 mA	Δλ		30		nm	
Temperature coefficient of Ip	I _F = 30 mA	ΤΚ _{λp}		0.25		nm	
Rise time	$I_F = 100 \text{ mA}, 20 \% \text{ to } 80 \%$	t _r		15		ns	
Fall time	I _F = 100 mA, 20 % to 80 %	t _f		15		ns	
Virtual source diameter		d		2		mm	



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BASIC CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)

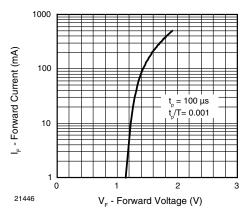


Fig. 3 - Forward Current vs. Forward Voltage

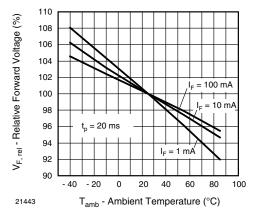


Fig. 4 - Relative Forward Voltage vs. Ambient Temperature

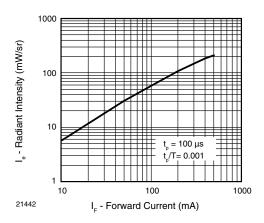


Fig. 5 - Radiant Intensity vs. Forward Current

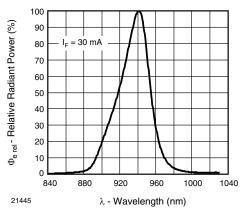


Fig. 6 - Relative Radiant Power vs. Wavelength

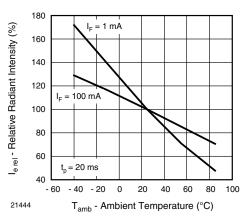


Fig. 7 - Relative Radiant Intensity vs. Ambient Temperature

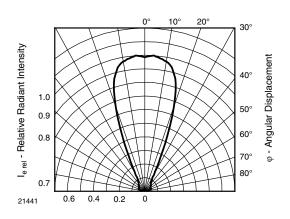


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

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For technical questions, contact: <u>emittertechsupport@vishay.com</u>

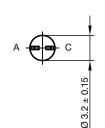
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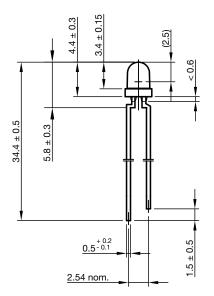
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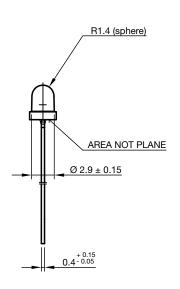


PACKAGE DIMENSIONS in millimeters

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technical drawings according to DIN specifications

Drawing-No.: 6.544-5255.01-4 Issue: 9; 28.07.14



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